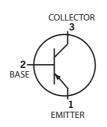
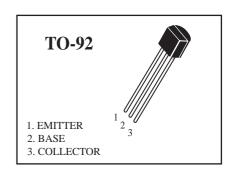




Plastic-Encapsulate Transistors PNP Silicon

Pb Lead(Pb)-Free





ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Rating	Symbol	SS8550	Unit
Collector-Emitter Voltage	VCEO	-25	Vdc
Collector-Base Voltage	V _{CBO}	-40	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current	lC	-1.5	Adc
Total Device Dissipation T _A =25 °C	PD	1.0	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

DEVICE MARKING

SS8550=SS8550D

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ⁽¹⁾ (I _C = -0.1 mAdc, I _B =0)	V(BR)CEO	-25	-	Vdc
Collector-Base Breakdown Voltage (I _C = -100 uAdc, I _E =0)	V _(BR) CBO	-40	-	Vdc
Emitter-Base Breakdown Voltage (I _E = -100 uAdc, I _C =0)	V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current (VCB= -40 Vdc, IE=0 Vdc)	ICBO	-	-0.1	uAdc
Emitter Cutoff Current(V _{EB} = -5 Vdc, I _C = 0 Vdc)	I _{EBO}	-	-0.1	uAdc

^{1.} Pulse Test: Pulse Width ≤ 300 us, Duty Cycle ≤2.0%

SS8550



$\textbf{ELECTRICAL CHARACTERISTICS} \text{ (T}_{A} = 25 ^{\circ} \text{C unless otherwise noted) (Countinued)}$

Characteristics	Symbol	Min	TYP	Max	Unit	1
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ON CHARACTERISTICS

DC Current Gain (I _C = -100 mAdc, V _{CE=-1.0} Vdc)	h _{FE(1)}	85	-	400	-
DC Current Gain (I _C = -800 mAdc, V _{CE} = -1.0 Vdc)	h _{FE(2)}	40	-	-	-
Collector-Emitter Saturation Voltage (I _C = -800 mAdc, I _B = -80 mAdc)	V _{CE(sat)}	-	-	-0.5	Vdc
Base-Emitter Saturation Voltage (I _C = -800 mAdc, I _B = -80 mAdc)	V _{BE(sat)}	-	-	-1.2	Vdc
Transition Frequency $(V_{CE}=-10V,I_C=-50mA,f=30 MHz)$	fŢ	100	-	-	MHz

Classification of $h_{FE(1)}$

Rank	В	С	D	E
Range	85-160	120-200	160-300	300-400



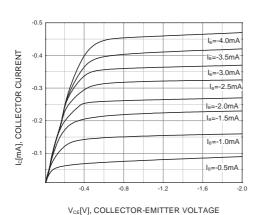


FIG.1 Static Characteristic

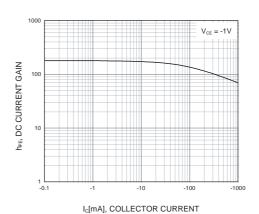


FIG.2 DC Current Gain

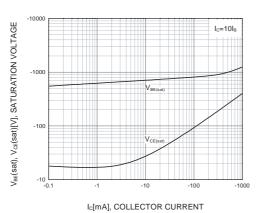


FIG.3 Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

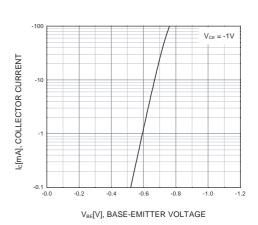


FIG.4 Base-Emitter On Voltage

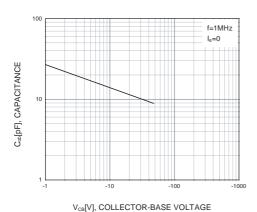


FIG.5 Collector Output Capacitance

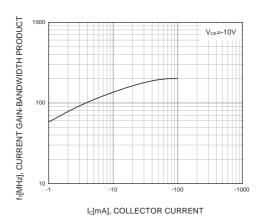
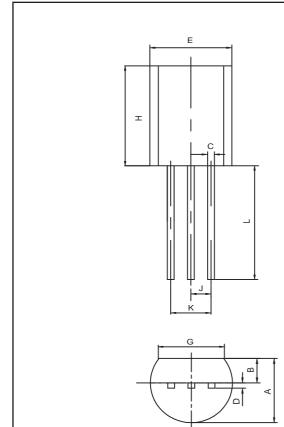


FIG.6 Current Gain Bandwidth Product



TO-92 Outline Dimensions

unit:mm



TO-92				
Dim	Min	Max		
A	3.30	3.70		
В	1.10	1.40		
C	0.38	0.55		
D	0.36	0.51		
E	4.40	4.70		
G	3.43 -			
H	4.30	4.70		
J	1.270TYP			
K	2.44	2.64		
L	14.10	14.50		